NPN Epitaxial Planar Silicon Transistor



2SD1806

# **High-Current Switching Applications**

# **Applications**

· Relay control, motor control, switching.

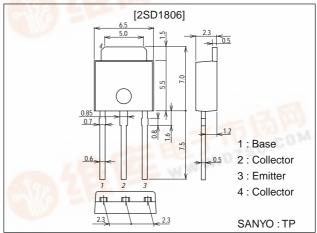
### **Features**

- · Low saturation voltage.
- · On-chip diode between collector and emitter.
- · Small and slim package permitting 2SD1806-applied sets to be made more compact.

# **Package Dimensions**

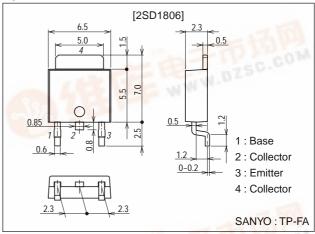
unit:mm

2045B



unit:mm

#### 2044B



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# **Specifications**

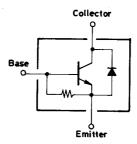
# Absolute Maximum Ratings at Ta = 25°C

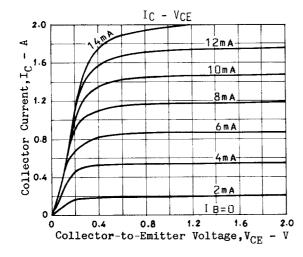
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		40	V
Collector-to-Emitter Voltage	VCEO		30	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		5	V
Collector Current	Ic		2	Α
Collector Current (Pulse)	I <sub>CP</sub>		4	Α
Collector Dissipation	PC		1	W
	''C	Tc=25°C	15	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

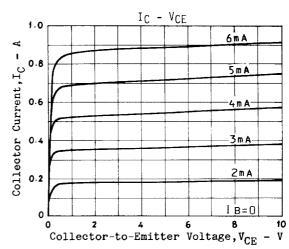
## Electrical Characteristics at Ta = 25°C

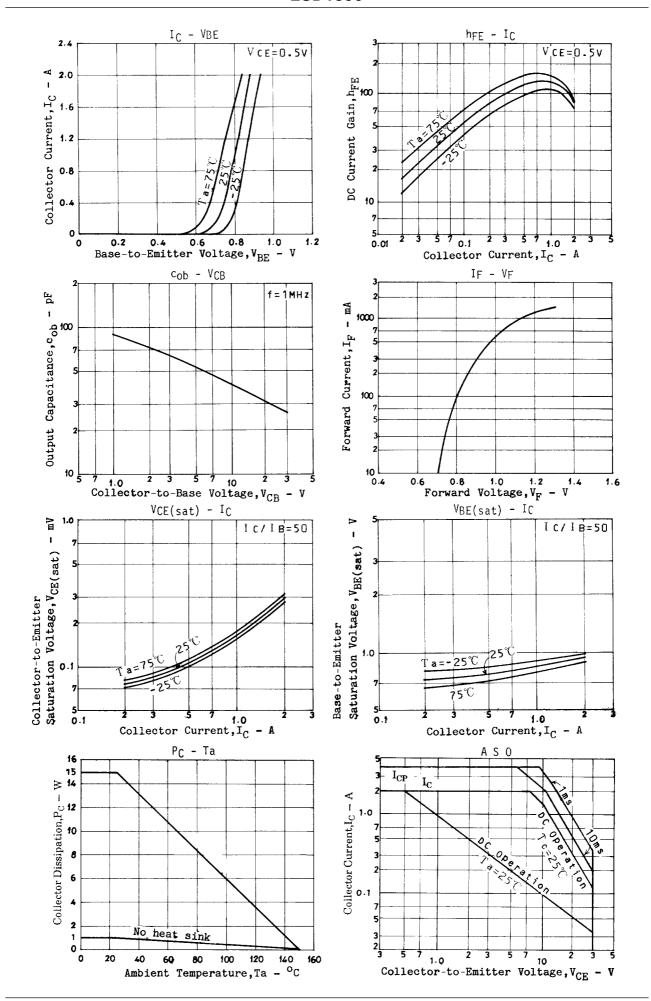
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Uill
Collector Cutoff Current	ICBO	V <sub>CB</sub> =20V, I <sub>E</sub> =0			1.0	μΑ
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =0.5V, I <sub>C</sub> =0.5A	50			
	h <sub>FE</sub> 2	V <sub>CE</sub> =0.5V, I <sub>C</sub> =2A	50			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =2V, I <sub>C</sub> =0.5A		150		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, f=1MHz		40		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =2A, I <sub>B</sub> =40mA		0.25	0.5	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =2A, I <sub>B</sub> =40mA		0.92	1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =10μA, I <sub>E</sub> =0	40			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =10mA, R <sub>BE</sub> =∞	30			V
Forward Voltage	٧F	I <sub>F</sub> =0.3A		0.9	1.2	V
Resistance between Base and Emitter	R <sub>BE</sub>			1.0		kΩ

## **Electrical Connection**









#### 2SD1806

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